# **High-Speed Switching** Diode

### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	100	V
Forward Current	١ <sub>F</sub>	200	mA
Non-Repetitive Peak Forward Surge Current 60 Hz	I <sub>FSM(surge)</sub>	1.8	A
Repetitive Peak Forward Current (Note 2)	I <sub>FRM</sub>	1.0	A
$\label{eq:surge} \begin{array}{l} Non-Repetitive Peak Forward Current \\ (Square Wave, T_J = 25^\circ C \mbox{ prior to} \\ surge) \\ t = 1  \\ t = 10  \\ t = 100  \\ t = 1  \\ t = 10  \\ t = 100  \\ t = 100  \\ t = 1  \\ \end{array}$	I <sub>FSM</sub>	36.0 18.0 6.0 3.0 1.8 1.3 1.0	A

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board T <sub>A</sub> = 25°C (Note 1)	PD	200	mW
Derate above 25°C		1.57	mW/°C
Thermal Resistance,	$R_{\theta JA}$		°C/W
Junction-to-Ambient		635	
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 Minimum Pad.

2. Square Wave, f = 40 kHz, PW = 200 ns

Test Duration = 60 s,  $T_J = 25^{\circ}C$  prior to surge.



# **ON Semiconductor®**

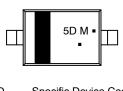
www.onsemi.com



SOD-323 CASE 477 STYLE 1



# **MARKING DIAGRAM**



5D = Specific Device Code Μ

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

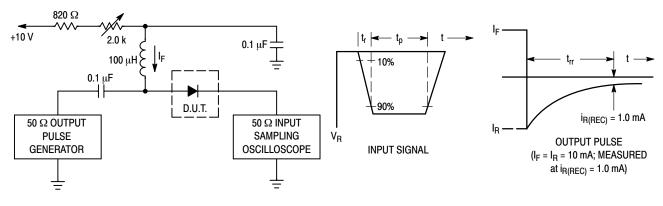
Device	Package	Shipping <sup>†</sup>
MMDL914T1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel
SMMDL914T1G	SOD-323 (Pb-Free)	3,000 / Tape & Reel
MMDL914T3G	SOD-323 (Pb-Free)	10,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMDL914

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage (I <sub>R</sub> = 100 μAdc)	V <sub>(BR)</sub>	100	-	Vdc
Reverse Voltage Leakage Current (V <sub>R</sub> = 20 Vdc) (V <sub>R</sub> = 75 Vdc)	I <sub>R</sub>		25 5.0	nAdc μAdc
Diode Capacitance (V <sub>R</sub> = 0 V, f = 1.0 MHz)	CT	-	4.0	pF
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	_	1.0	Vdc
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mAdc) (Figure 1)	t <sub>rr</sub>	_	4.0	ns



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA. 3. t<sub>p</sub> » t<sub>rr</sub>



## **MMDL914**

### **TYPICAL CHARACTERISTICS**

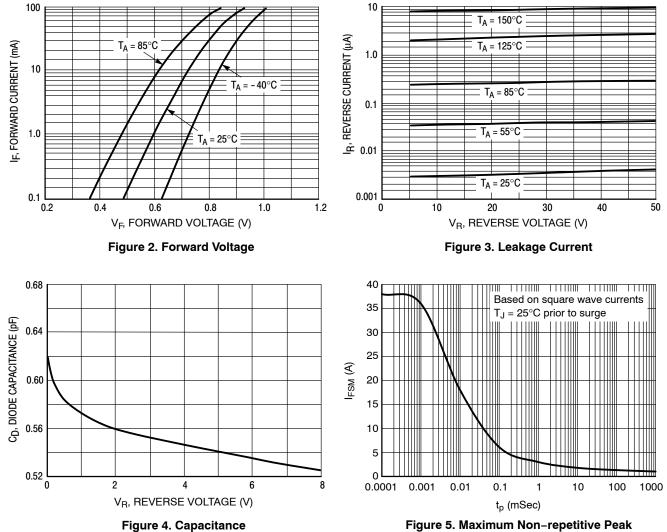
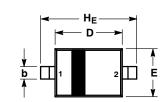


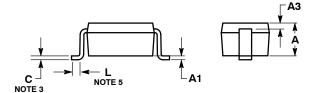
Figure 5. Maximum Non-repetitive Peak Forward Current as a Function of Pulse Duration, Typical Values



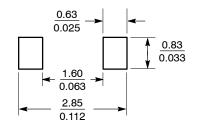








#### **SOLDERING FOOTPRINT\***



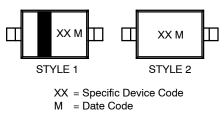
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 13 MAR 2007

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETERS.
  LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF		0	0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

#### GENERIC **MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE STYLE 2: NO POLARITY

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SOD-323 CASE 477-02

**ISSUE H** 

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